

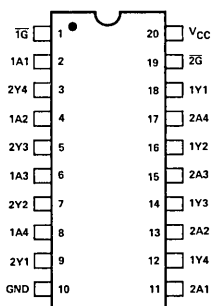
# AmZ8165 • AmZ8166

## Octal Dynamic Memory Drivers with Three-State Outputs

### DISTINCTIVE CHARACTERISTICS

- **Controlled rise and fall characteristics**  
Internal resistors provide symmetrical drive to HIGH and LOW states, eliminating need for external series resistor.
- **Output swings designed to drive 16K and 64K RAMs**  
 $V_{OH}$  guaranteed at  $V_{CC} - 1.15V$ . Undershoot going LOW guaranteed at less than 0.5V.
- **Large capacitive drive capability**  
35mA min source or sink current at 2.0V. Propagation delays specified for 50pF and 500pF loads.
- **Pin-compatible with 'S240 and 'S244**  
Non-inverting AmZ8166 replaces 74S244; inverting AmZ8165 replaces 74S240. Faster than 'S240/244 under equivalent load.
- **No-glitch outputs**  
Outputs forced into OFF state during power up and down.

### CONNECTION DIAGRAM Top View



Note: Pin 1 is marked for orientation.

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### FUNCTIONAL DESCRIPTION

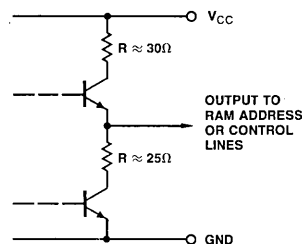
The AmZ8165 and AmZ8166 are designed and specified to drive the capacitive input characteristics of the address and control lines of MOS dynamic RAMs. The unique design of the lower output driver includes a collector resistor to control undershoot on the HIGH-to-LOW transition. The upper output driver pulls up to  $V_{CC} - 1.15V$  to be compatible with MOS memory and is designed to have a rise time symmetrical with the lower output's controlled fall time. This allows optimization of Dynamic RAM performance.

The AmZ8165 and AmZ8166 are pin-compatible with the popular 'S240 and 'S244 with identical 3-state output enable controls. The AmZ8165 has inverting drivers and the AmZ8166 has non-inverting drivers.

The inclusion of an internal resistor in the lower output driver eliminates the requirement for an external series resistor, therefore reducing package count and the board area required. The internal resistor controls the output fall and undershoot without slowing the output rise.

These devices are designed for use with the AmZ8164 Dynamic Memory Controller where large dynamic memories with highly capacitive input lines require additional buffering. Driving eight address lines or four  $\overline{RAS}$  and four  $\overline{CAS}$  lines with drivers on the same silicon chip also provides a significant performance advantage by minimizing skew between drivers. Each device has specified skew between drivers to improve the memory access worst case timing over the min and max  $t_{PD}$  difference of unspecified devices.

### TYPICAL OUTPUT DRIVER

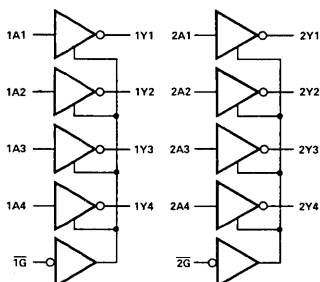


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### LOGIC DIAGRAMS

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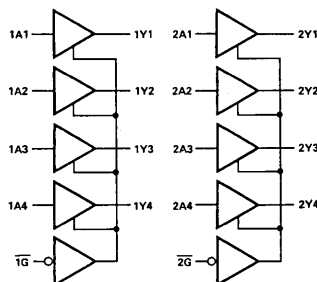
#### AmZ8165



| Inputs         |   | Outputs |
|----------------|---|---------|
| $\overline{G}$ | A | Y       |
| H              | X | Z       |
| L              | H | L       |
| L              | L | H       |

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#### AmZ8166



| Inputs         |   | Outputs |
|----------------|---|---------|
| $\overline{G}$ | A | Y       |
| H              | X | Z       |
| L              | L | L       |
| L              | H | H       |

**MAXIMUM RATINGS** (Above which the useful life may be impaired)

|   |                               |
|---|-------------------------------|
| Storage Temperature                                 | –65 to +150°C                 |
| Temperature (Ambient) Under Bias                    | –55 to +125°C                 |
| Supply Voltage to Ground Potential Continuous       | –0.5 to +7.0V                 |
| DC Voltage Applied to Outputs for High Output State | –0.5V to +V <sub>CC</sub> max |
| DC Input Voltage                                    | –0.5 to +7.0V                 |
| DC Output Current, into Outputs                     | 30mA                          |
| DC Input Current                                    | –30 to +5.0mA                 |

**ELECTRICAL CHARACTERISTICS**

The Following Conditions Apply Unless Otherwise Specified:

|       |                                |                             |              |              |
|-------|--------------------------------|-----------------------------|--------------|--------------|
| COM'L | T <sub>A</sub> = 0 to 70°C     | V <sub>CC</sub> = 5.0V ±10% | (MIN = 4.50V | MAX = 5.50V) |
| MIL   | T <sub>A</sub> = –55 to +125°C | V <sub>CC</sub> = 5.0V ±10% | (MIN = 4.50V | MAX = 5.50V) |

**DC CHARACTERISTICS OVER OPERATING RANGE**

| Parameters       | Description                           | Test Conditions (Note 1)  |                        | Min                                   | Typ<br>(Note 2)       | Max  | Units |
|------------------|---------------------------------------|---|------------------------|---------------------------------------|-----------------------|------|-------|
| V <sub>OH</sub>  | Output High Voltage                   | V <sub>CC</sub> = MIN<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OH</sub> = –1mA | V <sub>CC</sub> –1.15                 | V <sub>CC</sub> –0.7V |      | Volts |
| V <sub>OL</sub>  | Output LOW Voltage                    | V <sub>CC</sub> = MIN<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 1mA  |                                       |                       | 0.5  | Volts |
|                  |                                       |   | I <sub>OL</sub> = 12mA |                                       |                       | 0.8  |       |
| V <sub>IH</sub>  | Input HIGH Level                      | Guaranteed input logical HIGH voltage for all inputs                          |                        | 2.0                                   |                       |      | Volts |
| V <sub>IL</sub>  | Input LOW Level                       | Guaranteed input logical LOW voltage for all inputs                           |                        |                                       |                       | 0.8  | Volts |
| V <sub>I</sub>   | Input Clamp Voltage                   | V <sub>CC</sub> = MIN, I <sub>IN</sub> = –18mA                                |                        |                                       |                       | –1.2 | Volts |
| I <sub>IL</sub>  | Input LOW Current                     | V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4V                                 |                        |                                       |                       | –200 | μA    |
| I <sub>IH</sub>  | Input HIGH Current                    | V <sub>CC</sub> = MAX, V <sub>IN</sub> = 2.7V                                 |                        |                                       |                       | 20   | μA    |
| I <sub>I</sub>   | Input HIGH Current                    | V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0V                                 |                        |                                       |                       | 0.1  | mA    |
| I <sub>OZH</sub> | Off-State Current                     | V <sub>O</sub> = 2.7V   |                        |                                       |                       | 100  | μA    |
| I <sub>OZL</sub> | Off-State Current                     | V <sub>O</sub> = 0.4V   |                        |                                       |                       | –200 | μA    |
| I <sub>OL</sub>  | Output Sink Current                   | V <sub>OL</sub> = 2.0V  |                        | 35                                    |                       |      | mA    |
| I <sub>OH</sub>  | Output Source Current                 | V <sub>OH</sub> = 2.0V  |                        | –35                                   |                       |      | mA    |
| I <sub>SC</sub>  | Output Short Circuit Current (Note 3) | V <sub>CC</sub> = MAX   |                        | –60<br>(see I <sub>OH</sub> )         |                       | –200 | mA    |
| I <sub>CC</sub>  | Supply Current                        | AmZ8165   | All Outputs HIGH       | V <sub>CC</sub> = MAX<br>Outputs Open |                       | 24   | mA    |
|                  |                                       |   | All Outputs LOW        |                                       |                       | 86   |       |
|                  |                                       |   | All Outputs Hi-Z       |                                       |                       | 86   |       |
|                  |                                       | AmZ8166   | All Outputs HIGH       | V <sub>CC</sub> = MAX<br>Outputs Open |                       | 53   |       |
|                  |                                       |   | All Outputs LOW        |                                       |                       | 92   |       |
|                  |                                       |   | All Outputs Hi-Z       |                                       |                       | 116  |       |

Notes: 1. For conditions shown as MIN or MAX, use the appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical limits are at V<sub>CC</sub> = 5.0V, 25°C ambient and maximum loading.

3. Not more than one output should be shorted at a time. Duration of the short circuit test should not exceed one second.

SWITCHING CHARACTERISTICS

(T<sub>A</sub> = +25°C, V<sub>CC</sub> = 5.0V)

| Parameters        | Description                                    | Test Conditions  | Min                    | Typ | Max  | Units         |       |
|-------------------|--|--|------------------------|-----|------|---------------|-------|
| t <sub>PLH</sub>  | Propagation Delay Time from LOW-to-HIGH Output | Figure 1 Test Circuit<br>Figure 3 Voltage Levels and Waveforms | C <sub>L</sub> = 0pF   |     | 6    | (Note 4)      | ns    |
|                   |  |  | C <sub>L</sub> = 50pF  | 6   | 9    | 15            |       |
|                   |  |  | C <sub>L</sub> = 500pF | 15  | 22   | 35            |       |
| t <sub>PHL</sub>  | Propagation Delay Time from HIGH-to-LOW Output |  | C <sub>L</sub> = 0pF   |     | 4    | (Note 4)      | ns    |
|                   |  |  | C <sub>L</sub> = 50pF  | 6   | 12   | 20            |       |
|                   |  |  | C <sub>L</sub> = 500pF | 20  | 30   | 45            |       |
| t <sub>PLZ</sub>  | Output Disable Time from LOW, HIGH             | Figures 2 and 4, S = 1   |                        |     | 13   | 20            | ns    |
| t <sub>PHZ</sub>  |  | Figures 2 and 4, S = 2   |                        |     | 8    | 12            |       |
| t <sub>PZL</sub>  | Output Enable Time from LOW, HIGH              | Figures 2 and 4, S = 1   |                        |     | 13   | 20            | ns    |
| t <sub>PZH</sub>  |  | Figures 2 and 4, S = 2   |                        |     | 13   | 20            |       |
| t <sub>SKEW</sub> | Output-to-Output Skew                          | Figures 1 and 3, C <sub>L</sub> = 50pF                         |                        |     | ±0.5 | ±3.0 (Note 5) | ns    |
| V <sub>ONP</sub>  | Output Voltage Undershoot                      | Figures 1 and 3, C <sub>L</sub> = 50pF                         |                        |     | 0    | −0.5          | Volts |

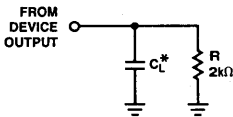
SWITCHING CHARACTERISTICS  
OVER OPERATING RANGE (Note 6)

|                  |  |  | COM'L   |      | MIL   |      |       |    |
|------------------|--|--|---|------|---|------|-------|----|
|                  |  |  | T <sub>A</sub> = 0 to 70°C<br>V <sub>CC</sub> = 5.0V ±10% |      | T <sub>A</sub> = −55 to +125°C<br>V <sub>CC</sub> = 5.0V ±10% |      |       |    |
| Parameters       | Description                                  | Test Conditions                        | Min   | Max  | Min   | Max  | Units |    |
| t <sub>PLH</sub> | Propagation Delay Time<br>LOW-to-HIGH Output | Figures 1 and 3                        | C <sub>L</sub> = 50pF                                     | 4    | 20  | 4    | 20    | ns |
|                  |  |  | C <sub>L</sub> = 500pF                                    | 13   | 40  | 13   | 40    |    |
| t <sub>PHL</sub> | Propagation Delay Time<br>HIGH-to-LOW Output | Figures 1 and 3                        | C <sub>L</sub> = 50pF                                     | 4    | 24  | 4    | 24    | ns |
|                  |  |  | C <sub>L</sub> = 500pF                                    | 17   | 50  | 17   | 50    |    |
| t <sub>PLZ</sub> | Output Disable Time from<br>LOW, HIGH        | Figures 2 and 4                        | S = 1   | 24   | 24  | ns   |       |    |
| t <sub>PHZ</sub> |  |  | S = 2   | 16   | 16  |      |       |    |
| t <sub>PZL</sub> | Output Enable Time from<br>LOW, HIGH         | Figures 2 and 4                        | S = 1   | 28   | 28  | ns   |       |    |
| t <sub>PZH</sub> |  |  | S = 2   | 28   | 28  |      |       |    |
| V <sub>ONP</sub> | Output Voltage Undershoot                    | Figures 1 and 3, C <sub>L</sub> = 50pF |   | −0.5 |   | −0.5 | Volts |    |

- Notes: 4. Typical time shown for reference only – not tested.  
5. Time Skew specification is guaranteed by design but not tested.  
6. AC performance over the operating temperature range is guaranteed by testing defined in Group A, Subgroup 9.

SWITCHING TEST CIRCUITS

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\*t<sub>pd</sub> specified at C = 50 and 500pF.

Figure 1. Capacitive Load Switching.

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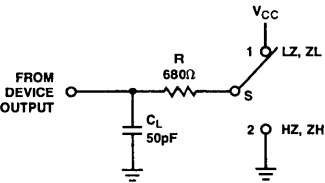
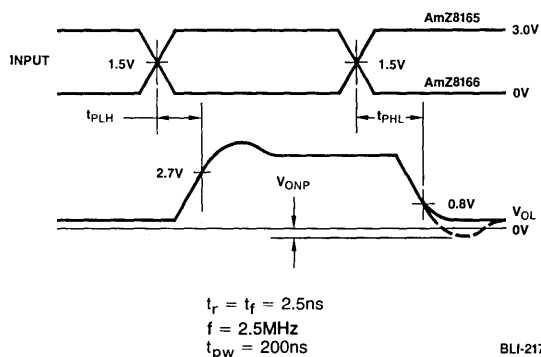


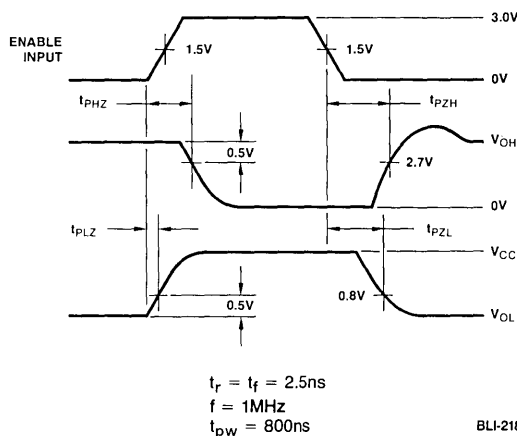
Figure 2. Three-State Enable/Disable.

## TYPICAL SWITCHING CHARACTERISTICS

## VOLTAGE WAVEFORMS



**Figure 3. Output Drive Levels.**

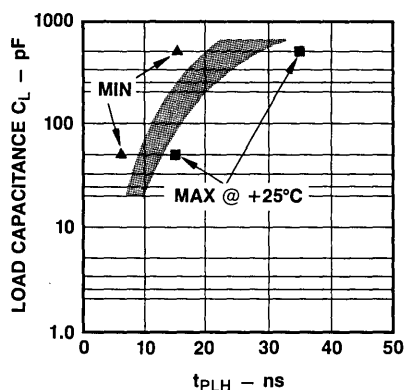


**Figure 4. Three-State Control Levels.**

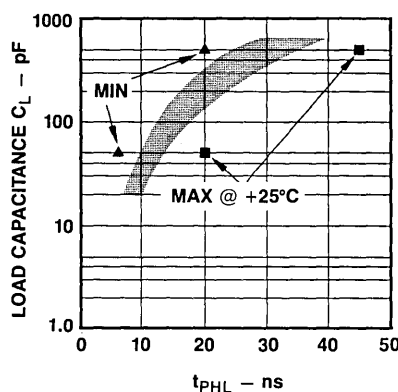
The RAM Driver symmetrical output design offers significant improvement over a standard Schottky output by providing a balanced drive output impedance ( $\approx 33\Omega$  both HIGH and LOW), and by pulling up to MOS  $V_{OH}$  levels ( $V_{CC} - 1.15V$ ). External resistors, not required with the RAM Driver, protect standard Schottky drivers from error causing undershoot but also slow the output rise by adding to the internal R.

The RAM Driver is optimized to drive LOW at maximum speed based on safe undershoot control and to drive HIGH with a symmetrical speed characteristic. This is an optimum approach because the dominant RAM loading characteristic is input capacitance.

The curves shown below provide performance characteristics typical of both the inverting (AmZ8165) and non-inverting (AmZ8166) RAM Drivers.



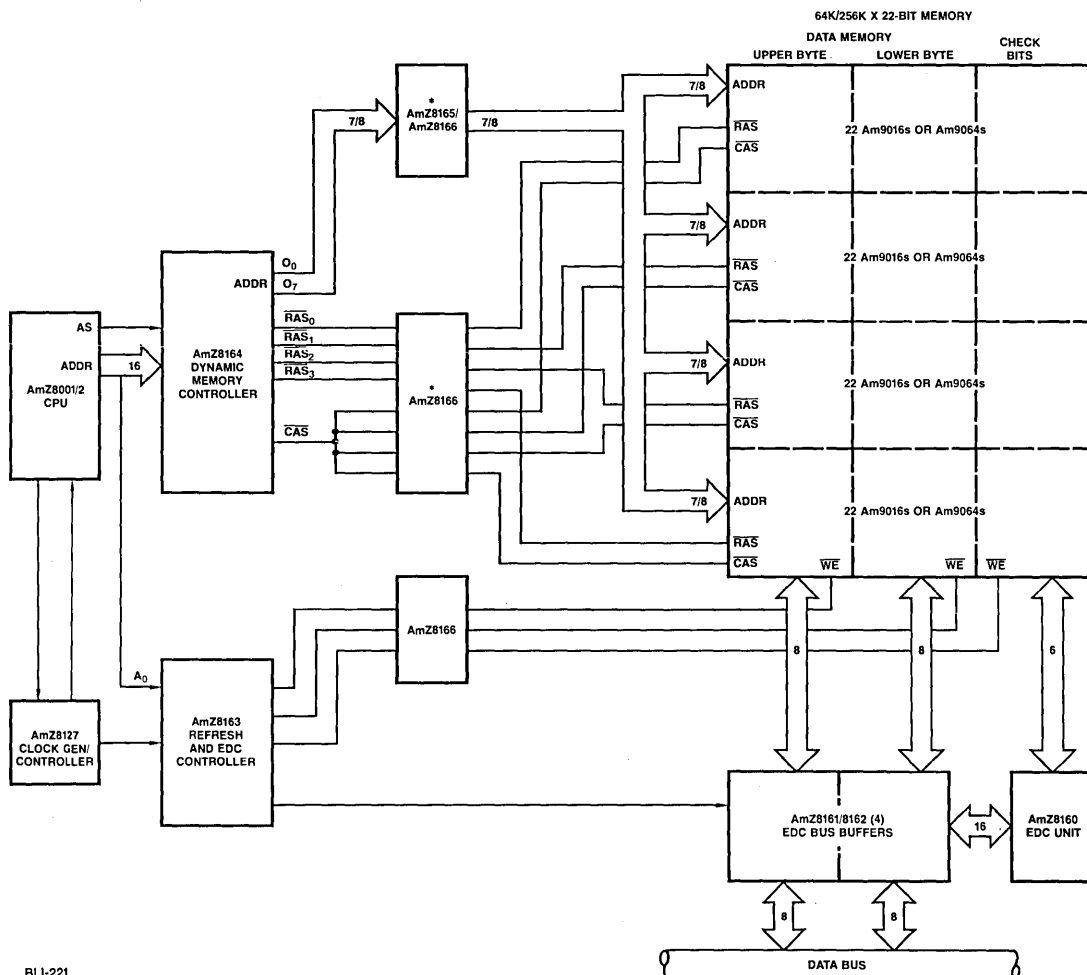
**Figure 5.  $t_{pLH}$  vs.  $C_L$ .**



**Figure 6.  $t_{PHL}$  vs.  $C_L$ .**

The curves above depict the typical  $t_{PLH}$  and  $t_{PHL}$  for the RAM Driver outputs as a function of load capacitance. The minimums and maximums are shown for worst case design. The typical band is provided as a guide for intermediate capacitive loads.

## APPLICATION



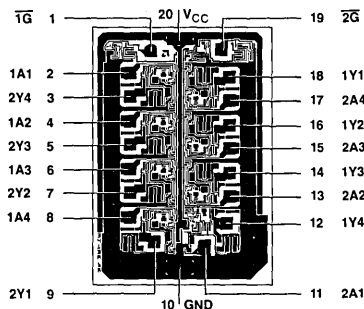
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\*Address and  $\overline{\text{RAS}}$ / $\overline{\text{CAS}}$  drivers each drive 22 RAM inputs at each output. Timing skew is minimized by using one device for address lines and one device for  $\overline{\text{RAS}}$ / $\overline{\text{CAS}}$ , spreading the  $\overline{\text{CAS}}$  loading over four drivers to equalize the capacitive load on each driver.

## DYNAMIC MEMORY CONTROL WITH ERROR DETECTION AND CORRECTION

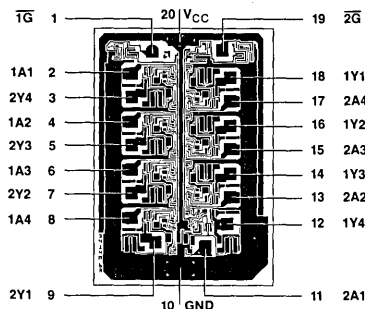
## Metallization and Pad Layouts

AmZ8165



DIE SIZE 0.094" X 0.060"

AmZ8166



DIE SIZE 0.094" X 0.060"

## ORDERING INFORMATION

Order the part number according to the table below to obtain the desired package, temperature range, and screening level.

| AmZ8165<br>Order Number | AmZ8166<br>Order Number | Package<br>Type | Temperature<br>Range | Screening<br>Level                                     |
|-------------------------|-------------------------|-----------------|----------------------|--|
| AMZ8165PC               | AMZ8166PC               | P-20            | C                    | C-1  |
| AMZ8165DC               | AMZ8166DC               | D-20            | C                    | C-1  |
| AMZ8165DM               | AMZ8166DM               | D-20            | M                    | C-3  |
| AMZ8165XC               | AMZ8166XC               | Dice            | C                    | } Visual Inspection<br>to MIL-STD-883<br>Method 2010B. |
| AMZ8165XM               | AMZ8166XM               | Dice            | M                    |  |

- Notes: 1. P = Molded DIP, D = Hermetic DIP. Number following letter is number of leads.  
 2. C = 0 to 70°C,  $V_{CC}$  = 4.50 to 5.50V, M = -55 to +125°C,  $V_{CC}$  = 4.50 to 5.50V.  
 3. Levels C-1 and C-3 conform to MIL-STD-883, Class C. Level B-3 conforms to MIL-STD-883, Class B.